

Long-wavelength Distributed Feedback Tapered QCLs

Daive Pinto^{1,2}

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3-8 September 2023

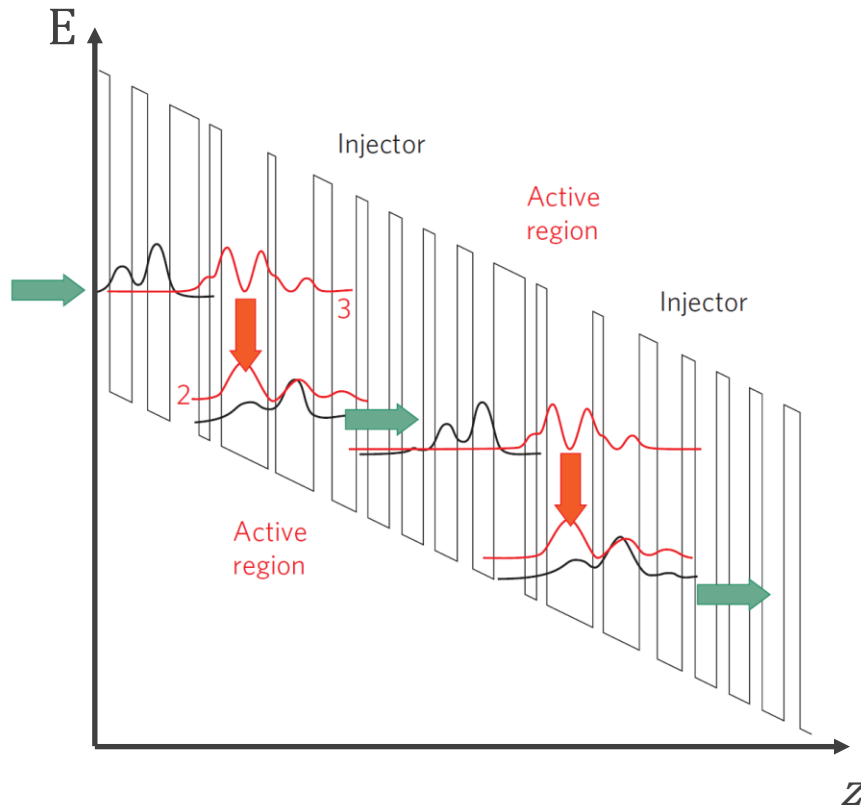
C-Pass: Conference on Photonics for Advanced Spectroscopy and Sensing



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Quantum cascade lasers (QCLs)



Yao, Y., Hoffman, A.J., Gmachl, C.F., 2012. *Nature Photonics* 6, 432–439.

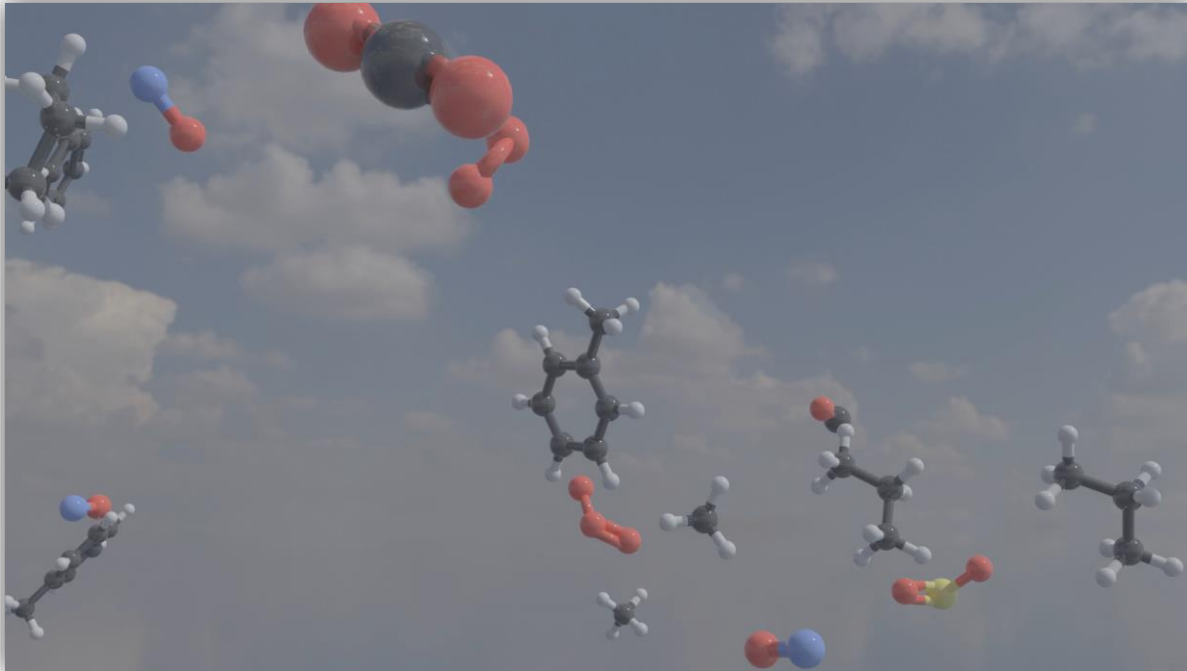
QCL'S MAIN CHARACTERISTICS

- “Artificial semiconductor” obtained as a repetition of quantum wells and barriers
- Photon are emitted by intersubband transition in a multistage-cascaded geometry
- Emission in the Mid-Infrared region:
 $\lambda = 2 \mu\text{m} - 24 \mu\text{m}$

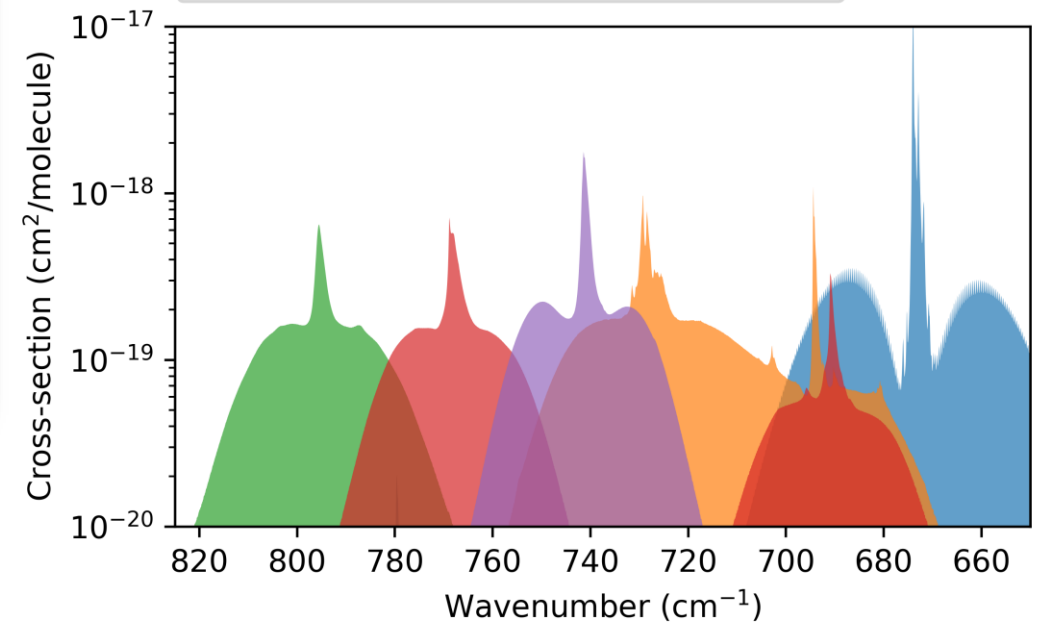
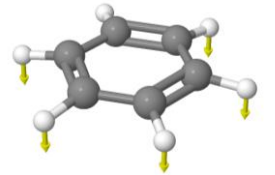


QCLs applications: spectroscopy

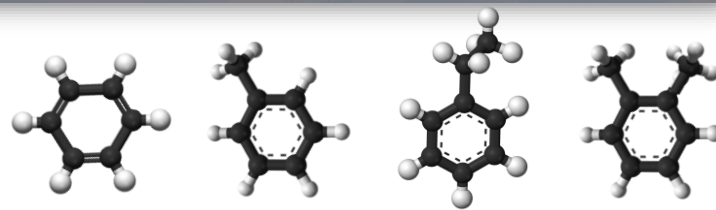
CHEMICAL SENSING (ENVIRONMENTAL MONITORING, HEALTH & LIFE SCIENCE)



- Benzene, $p=760.0$ Torr, $T=298.0$ K
- Toluene, $p=760.0$ Torr, $T=298.1$ K
- p-Xylene, $p=760.0$ Torr, $T=298.1$ K
- m-Xylene, $p=760.0$ Torr, $T=298.1$ K
- o-Xylene, $p=760.0$ Torr, $T=298.1$ K



BTEX COMPOUNDS



Benzene Toluene Ethylbenzene o-xylene

Slide 2

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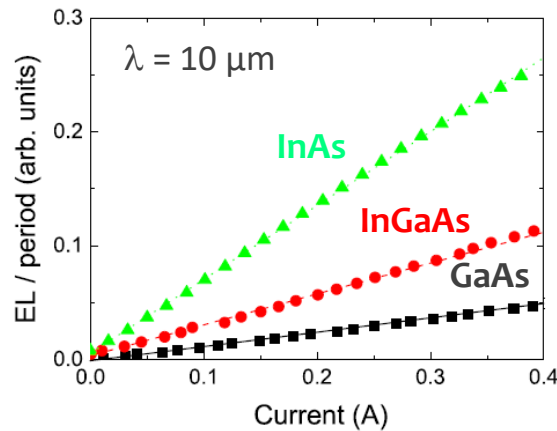
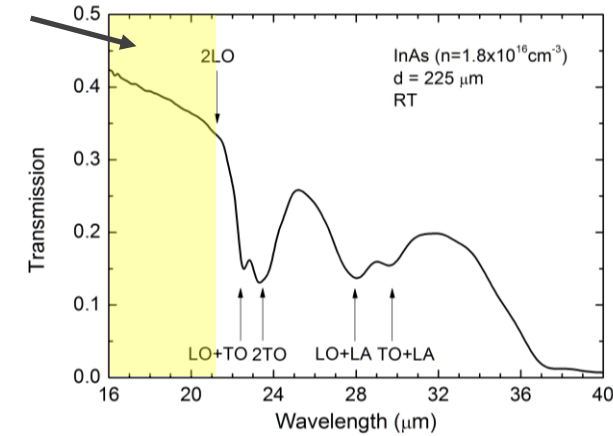


The Long-wavelength Challenge – InAs material system

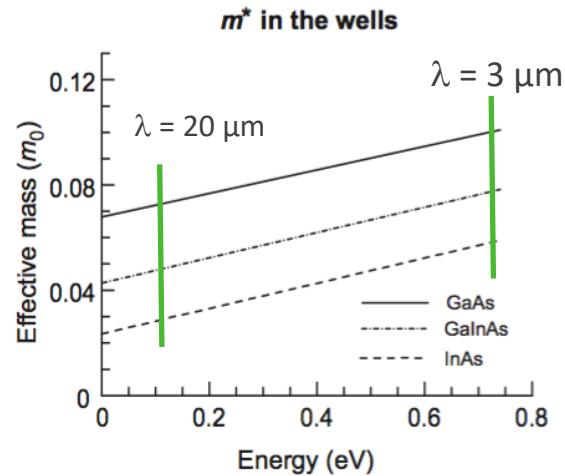
FACING THE LIMITATIONS:

Transparency
region in InAs

1. Smaller upper lifetimes (energy close to LO-phonon energy)
2. Free carrier scattering losses $\propto \lambda^2$
3. Material absorption (proximity to Reststrahlen band)



E. Benveniste et al., *Appl. Phys. Lett.* **93**, 131108 (2008) - MPQ



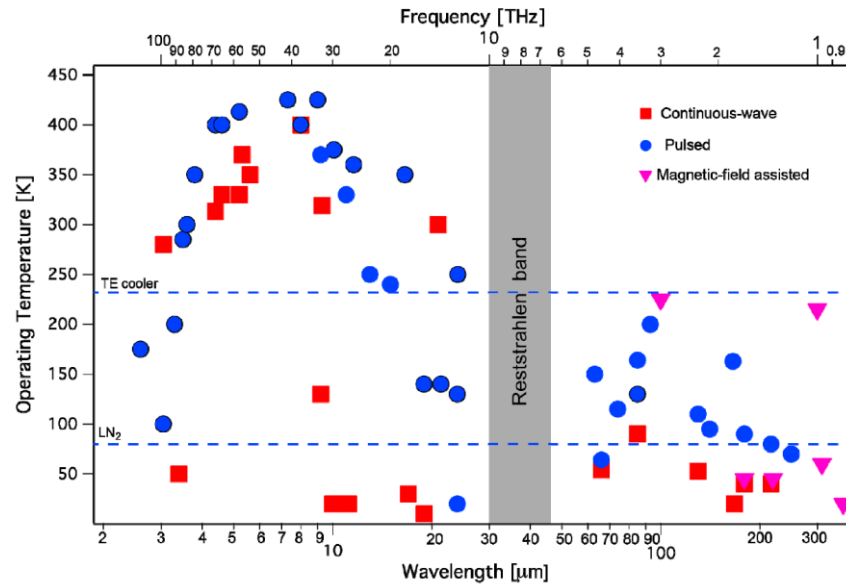
THE SOLUTION: HIGH GAIN MATERIAL

$$g = \frac{e\hbar}{\epsilon_0 c m_0} \frac{1}{2\gamma_{32} n L_p} f_{32} \tau_3 \left(1 - \frac{\tau_2}{\tau_{32}}\right) \sim \frac{1}{(m^*)^{3/2}}$$

- At larger wavelengths the non-parabolicity of the bands can be neglected
- Lower m^* in InAs than in other materials
- First long-wavelength QCLs demonstrated at **Université de Montpellier**, since 2013



The strive toward higher optical power



Quantum Cascade Lasers: 20 years of challenges, *Opt. Exp.* 2015

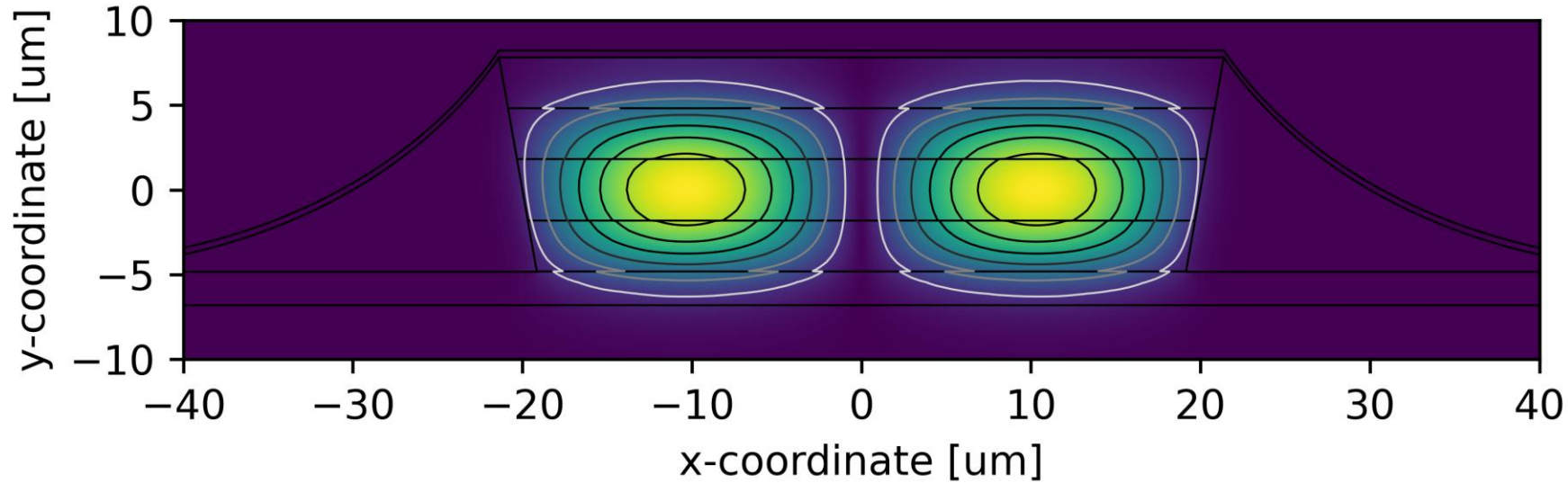
- Thermally activated processes (such as backfilling) reduce the laser performance at higher λ ;
- The material system and heat extraction technology also play a fundamental role for CW-operation;
- Reduced optical power:

$$P_{opt} = F_{ph} \hbar \omega \propto \frac{1}{\lambda}$$

NEED OF A STRATEGY TO IMPROVE AVAILABLE POWER!



The strive toward higher optical power



BEAM QUALITY FACTOR

$$M_{x,y}^2 = \frac{4\pi\sigma_{0(x,y)}\sigma_{\theta(x,y)}}{\lambda}$$

NARROW RIDGE WIDTH



diffraction limited beam quality ($M^2 \approx 1$)

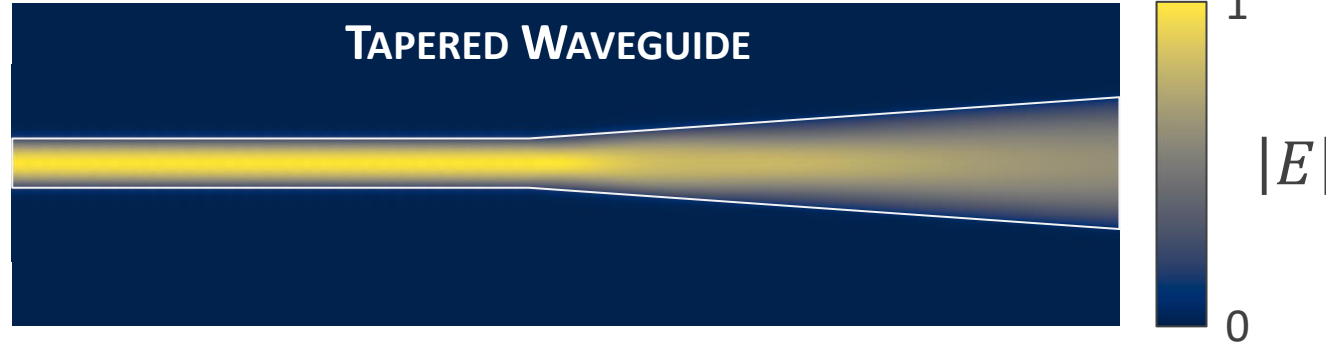
WIDE RIDGE WIDTH



waveguide supports higher order modes ($M^2 \gg 1$)



MOPAs & Tapered lasers



ADVANTAGES OF TAPERED WAVEGUIDE:

1. Larger active zone
2. Good Beam quality
3. Reduced in-plane divergence

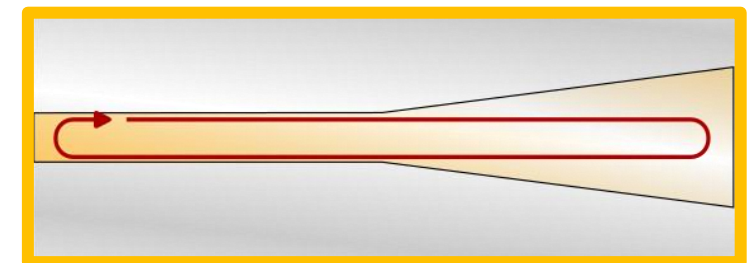
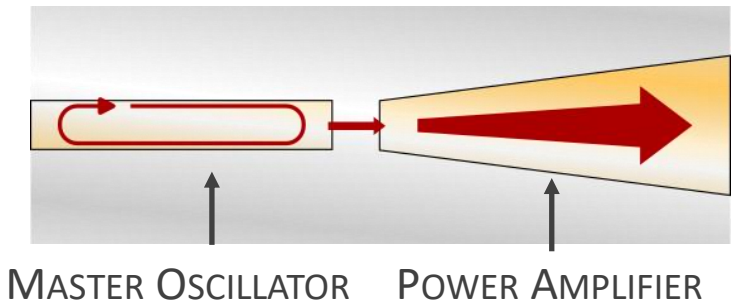
MASTER OSCILLATOR

POWER AMPLIFIER:

- PA is driven below self-lasing current density
- Individual components optimization
- Adds complexity

TAPERED LASER:

- the tapered waveguide acts as a (unstable) laser cavity
- Monolithic device



Fabrication of LW-Tapered QCLs

TAPERED GEOMETRY:

- 3.6 mm long laser bars
- Taper (full-)angles between 0° – 3°
- Linear taper geometry
- $\frac{1}{2}$ Taper section
 $\frac{1}{2}$ Ridge section



Laser	Taper angle
A	0°
B	1°
C	2°
D	3°



Fabrication of LW-Tapered QCLs

0. Grating fabrication via
electron-beam lithography



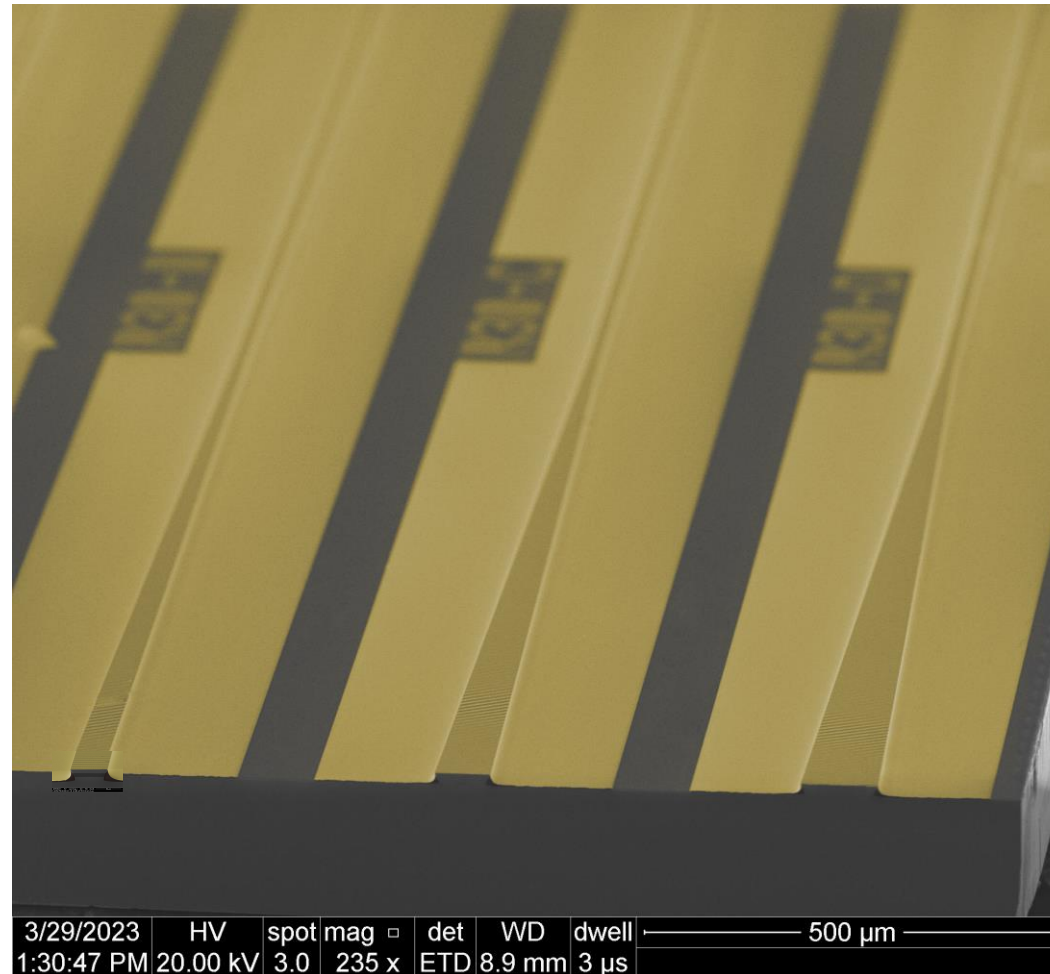
1. Deep wet MESA etching



2. Insulation via resist hard-bake



3. Top contact metalization



- InAs Cladding (doped)
- InAs Spacer (undoped)
- InAs/AlSb active zone
- Baked resist
- Gold metalization



Fabrication of LW-Tapered QCLs

FABRICATION PROCESS:

0. Grating fabrication via
electron-beam lithography



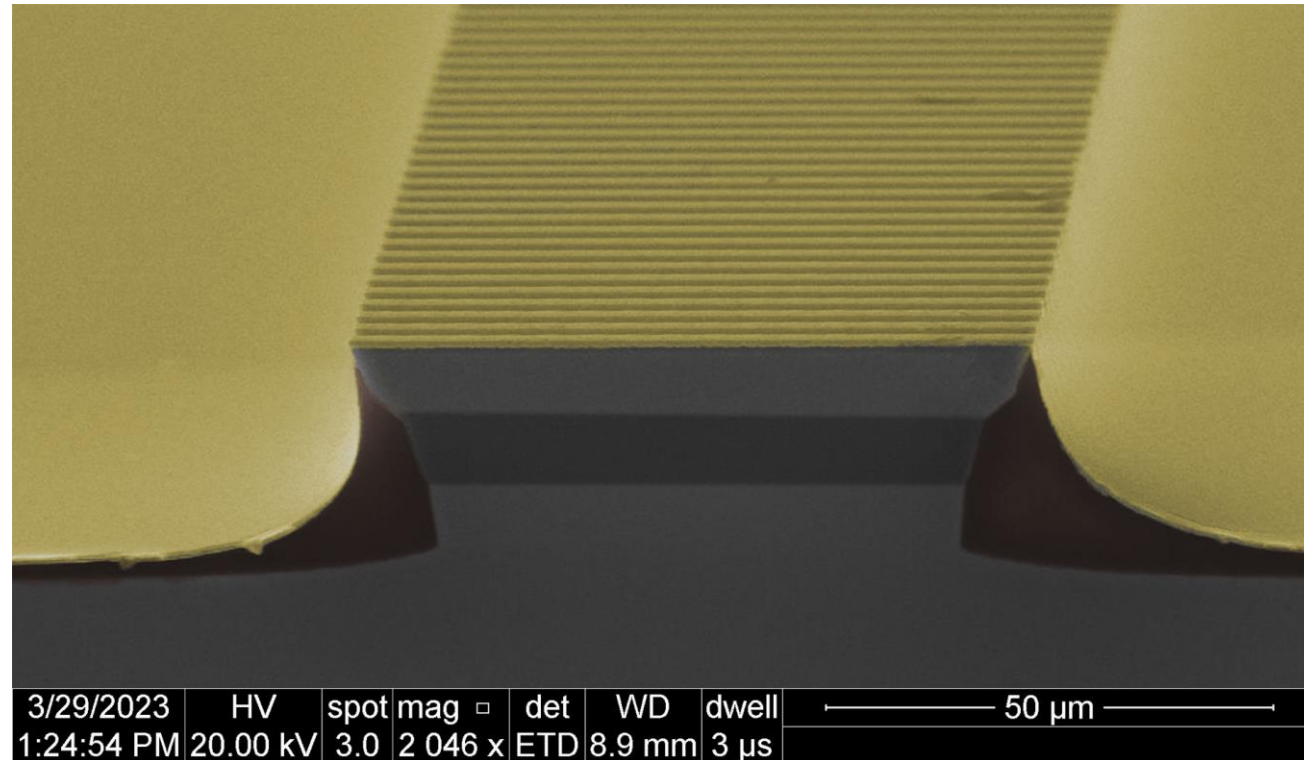
1. Deep wet MESA etching



2. Insulation via resist hard-bake



3. Top contact metalization



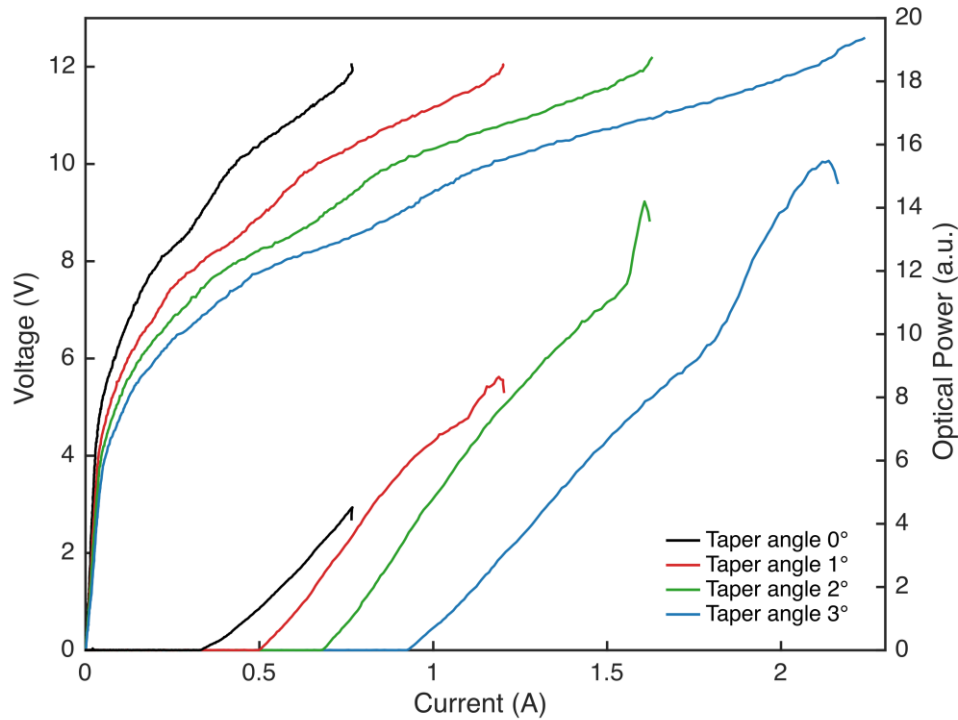
dding (doped)
cer (undoped)
b active zone
esist
talization



Optical Power enhancement

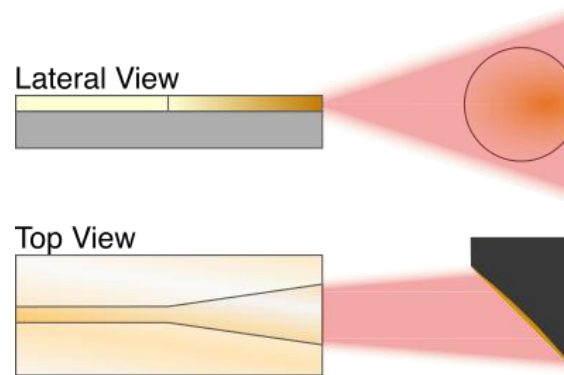
LIV OF FABRY-PÉROT TAPERED QCLS

PULSED OPERATION (PRR = 12 KHZ, dt = 330 ns)
ROOM TEMPERATURE

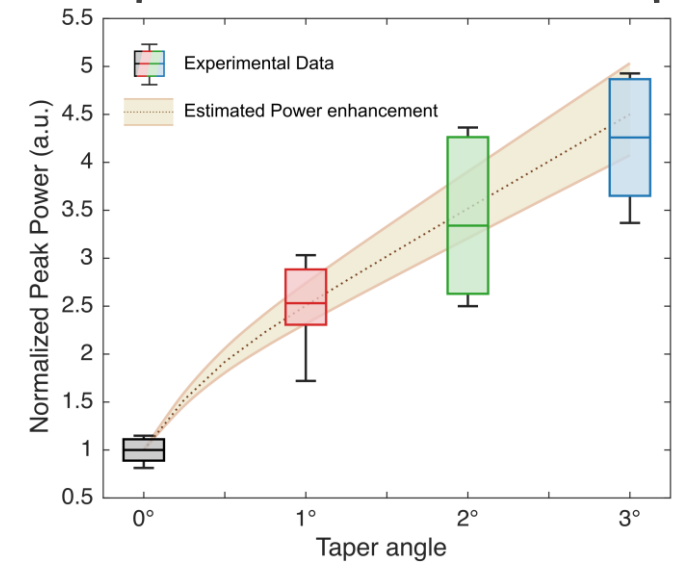


The observed total output is a **combination** of:

1. larger **active area**
2. higher **collection efficiency**



Non-linear enhancement of the collection efficiency Linear enhancement from active volume increase



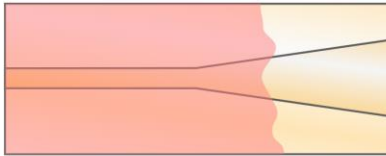
*Ridge width= 14 um, Laser Length 3.6mm, Taper section 50%

Taper angle	Active volume enhancement*	Collection efficiency*	Estimated power enhancement*
0°	1	1	1
1°	1.56	1.48	2.3
2°	2.12	1.51	3.2
3°	2.68	1.52	4.1

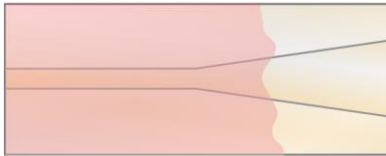
Anti- & High-reflection Coatings

AR-coating

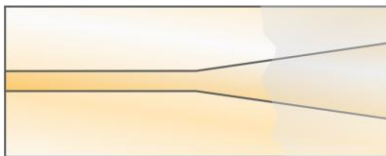
1. Resist protection



2. SiO₂ sputtering

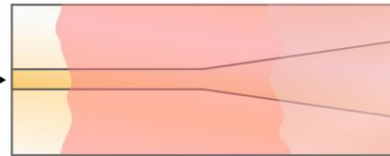


3. Resist lift-off



HR-coating

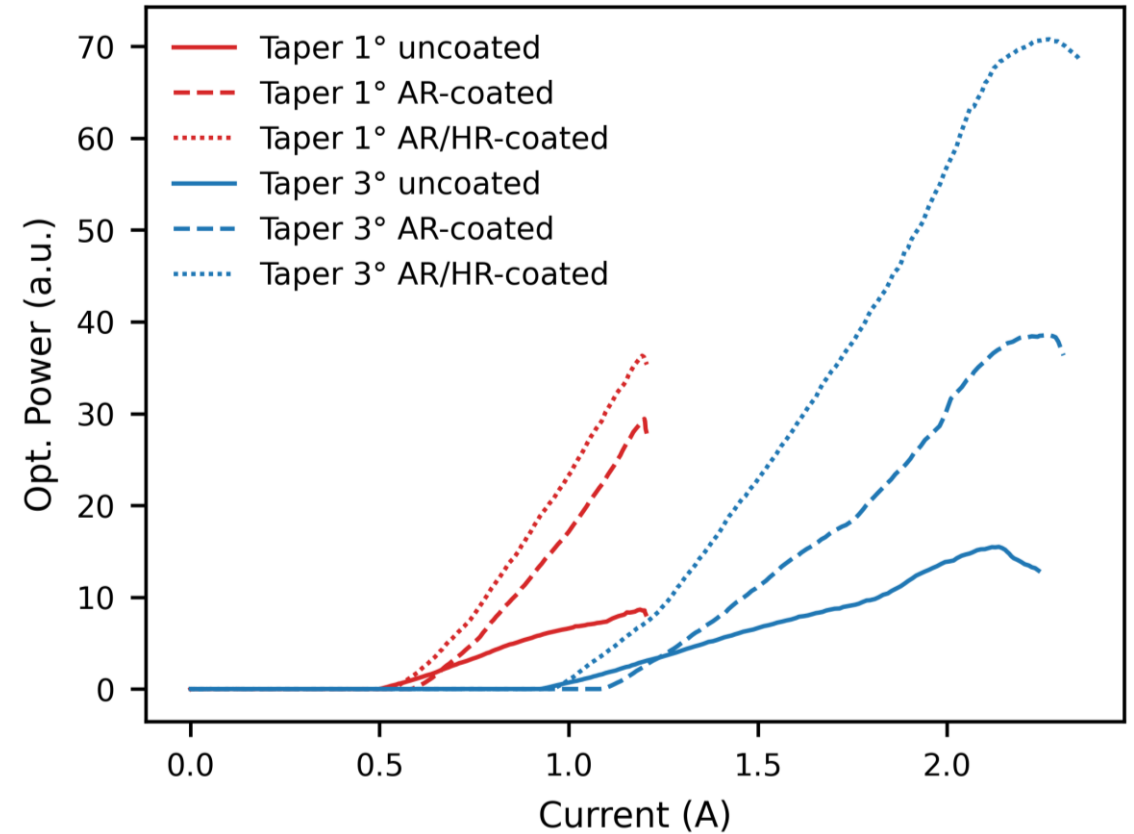
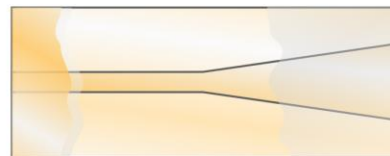
4. Resist Protection



5. SiO₂/Au sputtering



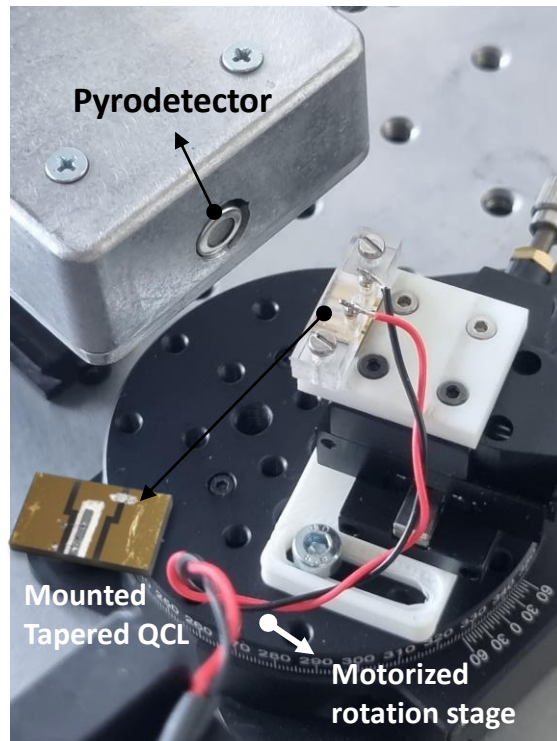
6. Resist lift-off



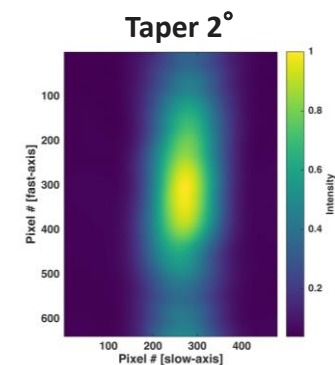
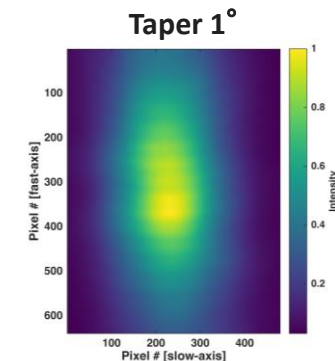
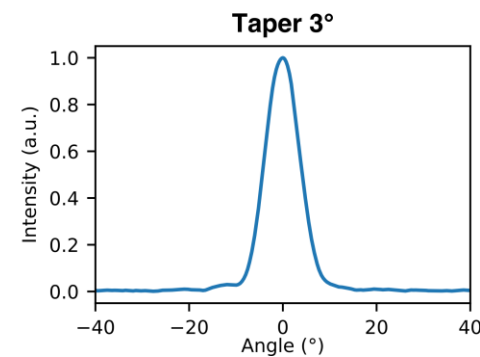
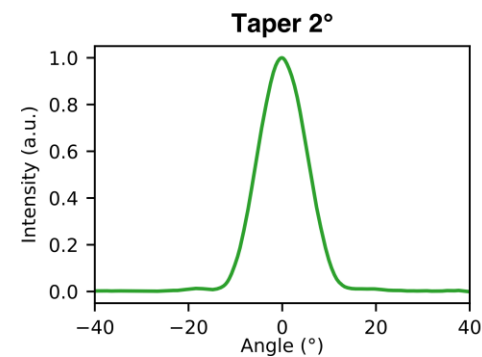
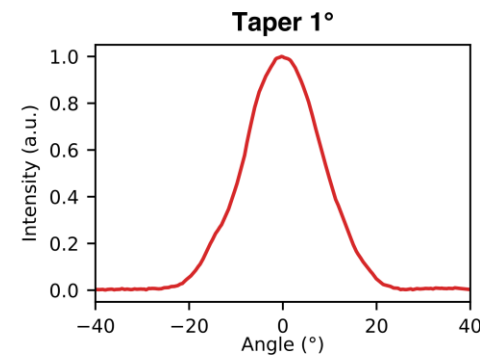
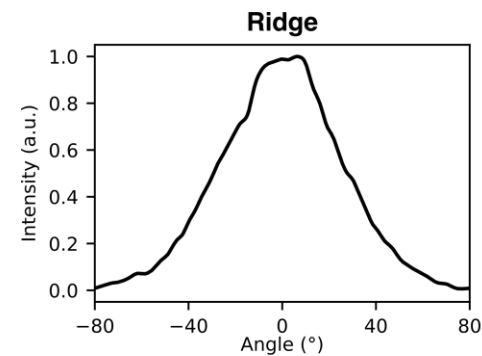
TAPERED LASERS PROVIDED HIGHER OPTICAL POWER OUTPUT THAN RIDGE LASERS

Divergence angle and beam quality estimation

MEASUREMENT SETUP



DIVERGENCE ANGLE RESULTS



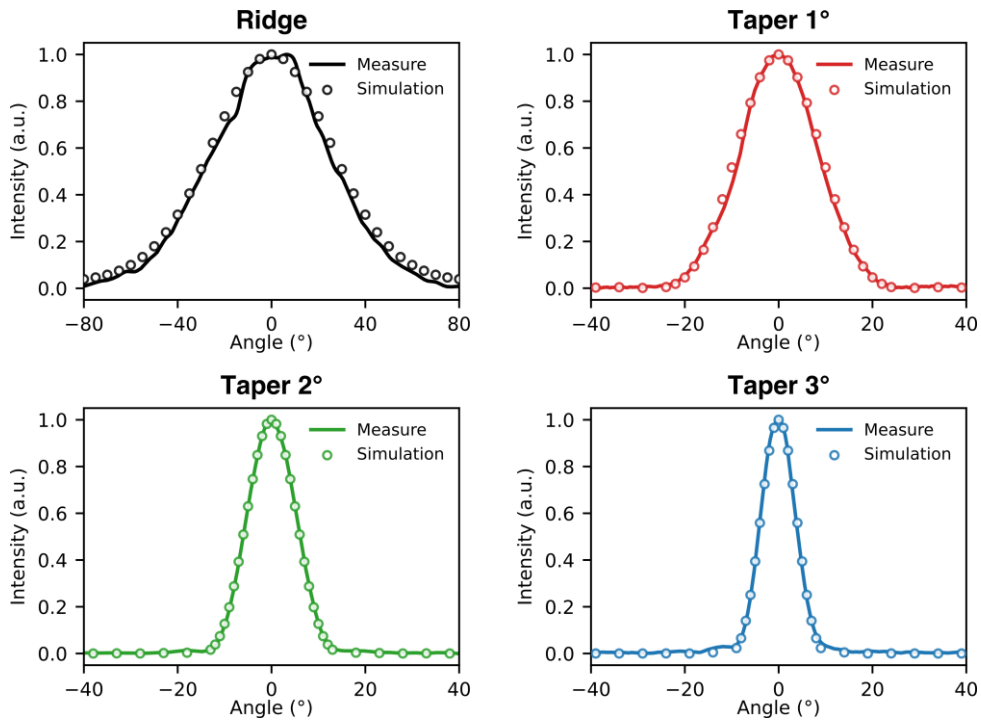
FEATURES

- **Narrower** slow-axis divergence for tapered devices
- **Single lobe** distributions
- **Absence** of higher-order modes also along **fast-axis**

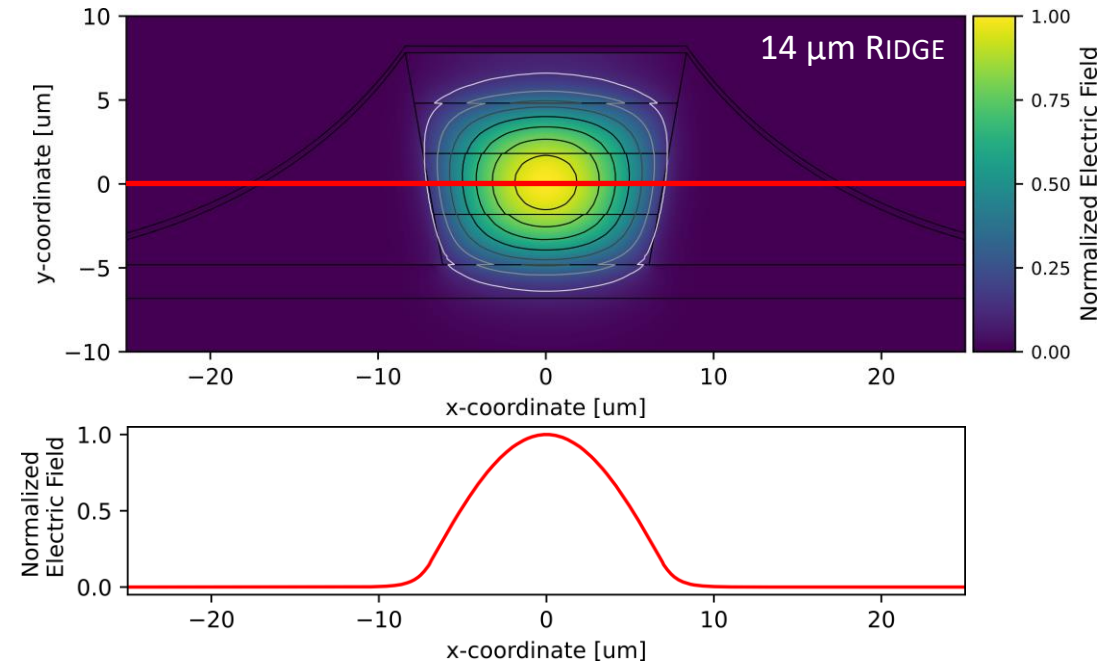


Divergence angle and beam quality estimation

DIVERGENCE ANGLE RESULTS



MODE ANALYSIS



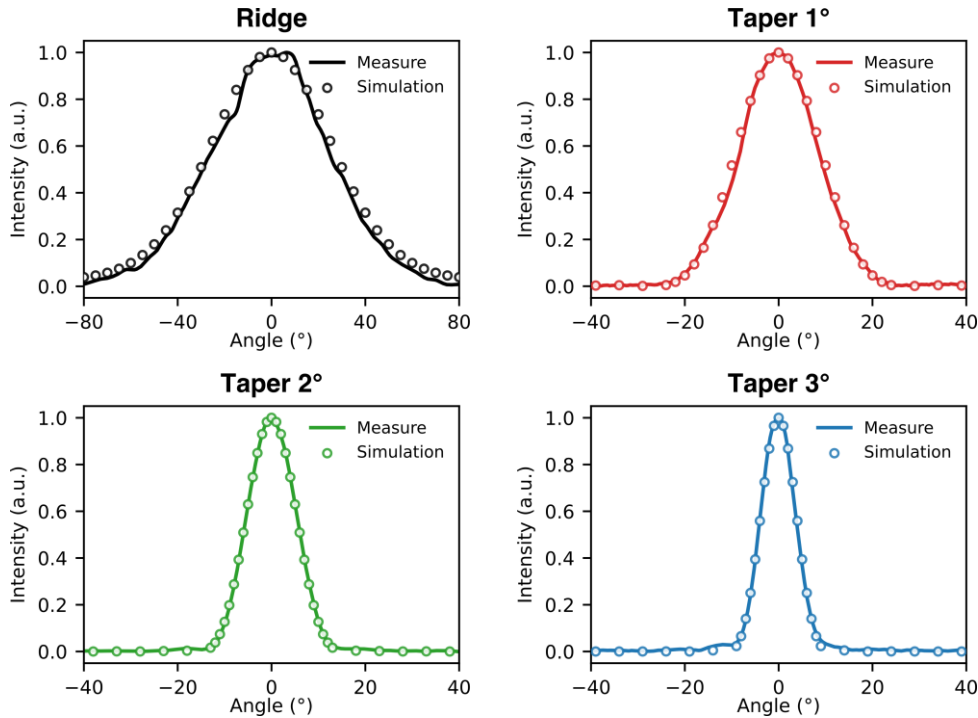
NEAR-FIELD TO FAR-FIELD DISTRIBUTIONS

$$P(k_x) = \int_{-\infty}^{+\infty} E(x) e^{ik_x x} dx \quad \longrightarrow \quad P^2(\theta) = \left| \int_{-\infty}^{+\infty} E(x) e^{i \frac{2\pi}{\lambda_0} \sin(\theta) x} dx \right|^2$$



Divergence angle and beam quality estimation

DIVERGENCE ANGLE RESULTS



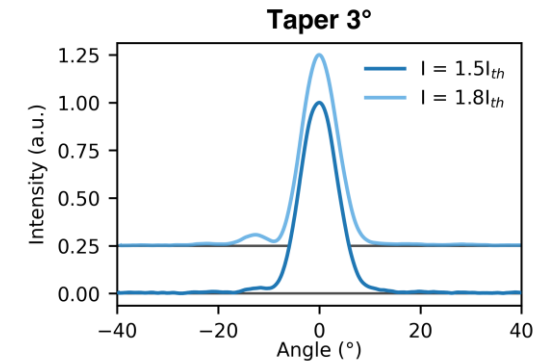
BEAM QUALITY FACTOR

$$M^2 = \frac{4\pi\sigma_0\sigma_\theta}{\lambda}$$

SECOND ORDER MOMENTUM (σ_0, σ_θ)

$$\sigma_\theta^2 = \frac{\int_{-\infty}^{+\infty} (\theta - \bar{\theta})^2 I(\theta) d\theta}{\int_{-\infty}^{+\infty} I(\theta) d\theta}$$

Taper angle	σ_θ	M^2
0°	~26°	~1
1°	8.03°	1.02
2°	5.06° → 5.13°	1.07 → 1.08
3°	4.23° → 4.80°	1.29 → 1.46

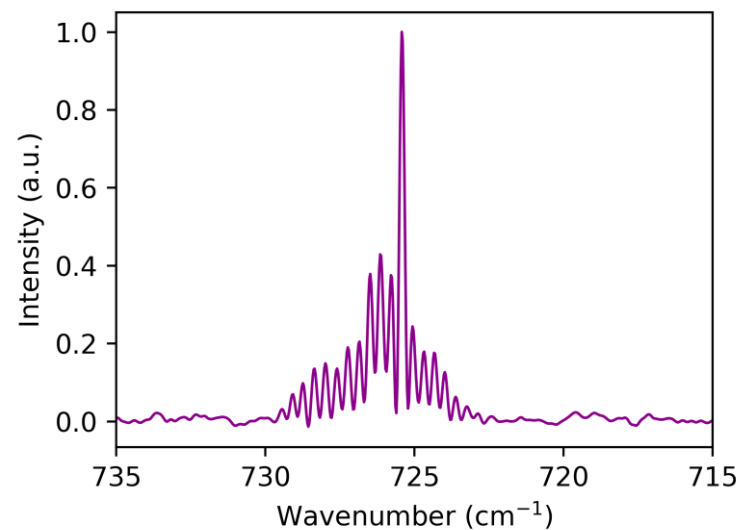


(LOW BIAS CURRENT → HIGH BIAS CURRENT)

DIFFRACTION LIMITED BEAM QUALITY, ASIDE FROM 3° TAPERS

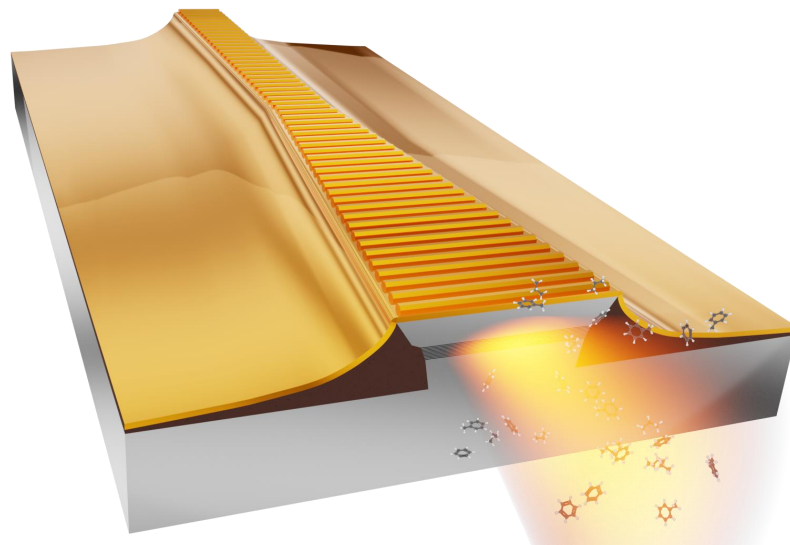
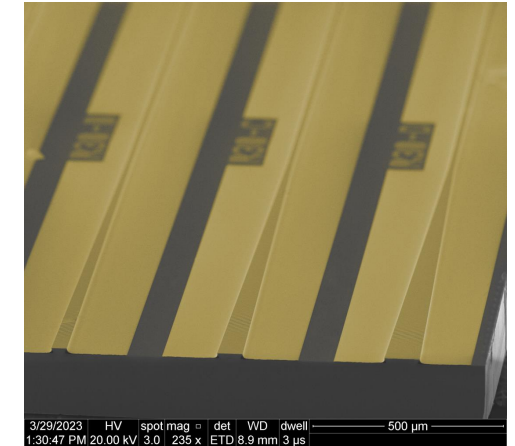
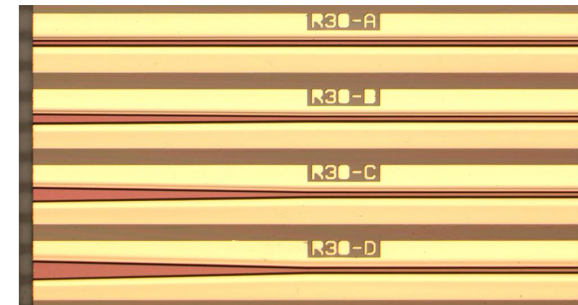
Distributed Feedback Tapered QCLs

Fabry-Pérot Spectrum



CONCLUSIONS

- First demonstration of DFB tapered lasers in the long-wavelength infrared region
- **Diffraction-limited beam quality** was achieved, together with **single-longitudinal mode operation**



OUTLOOKS

- Optimize taper geometry to achieve higher performances, especially for CW-operation
- Employment of the DFB-tapered lasers for spectroscopy of BTEX compounds





Thanks for your attention

